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General purpose high voltage amplifier in bare die form

Complement to NPN MPSA05

Features:

- 60 Volt V_{CEO}
- Low V_{CE(sat)}
- Characterized at temperature extremes
- High Reliability Gold Back Metal
- High Reliability tested grades for Military + Space

Ordering Information:

The following part suffixes apply:

- No suffix MIL-STD-750 /2072 Visual Inspection
- "H" MIL-STD-750 /2072 Visual Inspection+ MIL-STD-38534 Class H LAT
- "K" MIL-STD-750 /2072 Visual Inspection+ MIL-STD-38534 Class K LAT

LAT = Lot Acceptance Test.

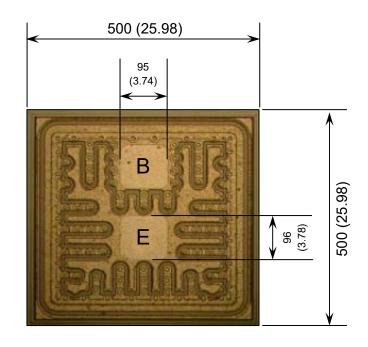
For further information on LAT process flows see below.

www.siliconsupplies.com\quality\bare-die-lot-qualification

Supply Formats:

- Default Die in Waffle Pack (400 per tray capacity)
- Sawn Wafer on Tape Specific request
- Unsawn Wafer Specific request
- With additional electrical selection Specific request
- Sawn as pairs or adjacent pair pick Specific request

Die Dimensions in µm (mils)



 $\mathbf{E} = \mathbf{EMITTER} \ \mathbf{B} = \mathbf{BASE}$

DIE BACK = COLLECTOR

Mechanical Specification

Die Size (Excluding Saw Street)	500 x 500 19.69 x 19.69	μm mils	
Base & Emitter Pad Size	95 x 96 3.74 x 3.78	μm mils	
Die Thickness	180 (±20) 7.09 (±0.79)	μm mils	
Top Metal Composition	Al - 2.6μm		
Back Metal Composition	AuAs - 0.9μm		





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Absolute Maximum Ratings T_A = 25°C unless otherwise stated

PARAMETER	SYMBOL	VALUE	UNIT
Collector-Base Voltage	V _{CBO}	-60	V
Collector-Emitter Voltage	V _{CEO}	-60	V
Emitter-Base Voltage	V _{EBO}	-4	V
Collector Current	Ic	-500	mA
Junction Temperature	TJ	150	°C
Storage Temperature	T _{stg}	-55 to 150	°C

Electrical Characteristics T_A = 25°C unless otherwise stated

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT	
OFF CHARACTERISTICS							
Collector-Base Breakdown Voltage	V _{(BR)CBO}	I _C = -100μA	-60	-	-	V	
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	$I_C = -1mA$	-60	-	-	V	
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	I _E = -100μA	-5	-	-	V	
Collector Cut-off Current	I _{CBO}	V _{CB} = -60V	-	-	-100	nA	
Emitter Cut-off Current	I _{CEO}	V _{EB} = -60V	-	-	-100	nA	
ON CHARACTERISTICS							
Forward-Current Transfer Ratio	h _{FE}	$V_{CE} = -1V, I_{C} = -10mA$	100	-	-	-	
		$V_{CE} = -1V, I_{C} = -100 \text{mA}$	100	-	-	-	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	I _C = -100mA, I _B = -10mA	-	-	-0.25	V	
Base Saturation Voltage	V _{BE(sat)}	I _C = -100mA, V _{CE} = -1V	-	-	-1.2	V	
SMALL SIGNAL CHARACTERISTICS ¹							
Transition Frequency	f⊤	V _{CE} = -1V, I _C = -100mA, f = 100MHz	50	70	-	MHz	
Output Capacitance	C _{obo}	$V_{CB} = -20V, I_E = 0, f = 1MHz$	-	3.5	-	pF	

Note 1: Not production testing in die form. Characterized by chip design and tested in package LAT.

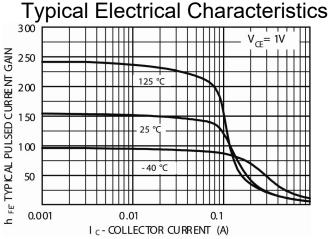


Fig 1 - Typical Pulsed Current Gain versus Collector Current

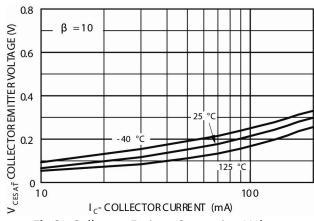


Fig 2 - Collector-Emitter Saturation Voltage versus Collector Current





Typical Electrical Characteristics (Continued)

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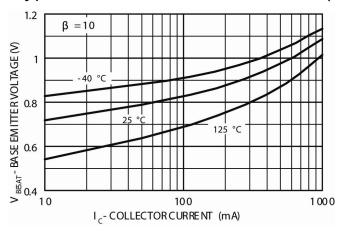


Fig 3 - Base-Emitter Saturation Voltage versus Collector Current

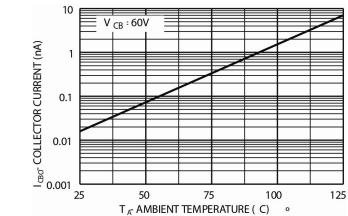


Fig 5 - Collector-Cut-off Current versus Ambient Temperature

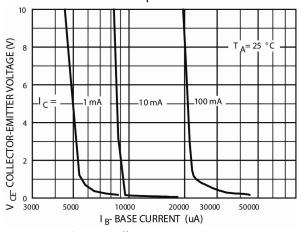


Fig 7 – Collector Saturation region

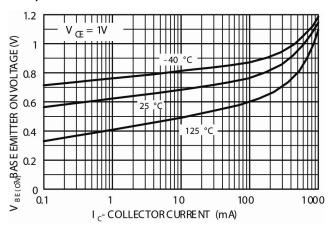


Fig 4 - Base-Emitter ON Voltage versus Collector Current

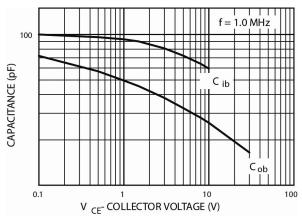


Fig 6 – Input and Output Capacitance versus Reverse Voltage

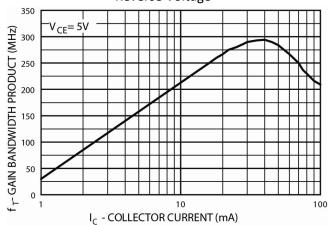


Fig 8 – Gain Bandwidth Product versus Collector Current





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